

Features

- Trench Power LV MOSFET Technology
- · Excellent Package for Heat Dissipation
- High Density Cell Desihn for Low R_{DS(on)}
- Epoxy Meets UL 94 V-0 Flammability Rating
- · Moisture Sensitivity Level 1
- Halogen Free Available Upon Request By Adding Suffix "-HF"
- Lead Free Finish/RoHS Compliant ("P" Suffix Designates RoHS Compliant. See Ordering Information)

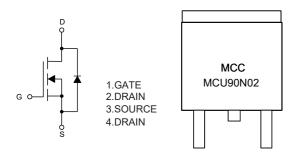
Maximum Ratings

- Operating Junction Temperature Range : -55°C to +175°C
- Storage Temperature Range: -55°C to +175°C
- Thermal Resistance: 3.3°C/W Junction to Case

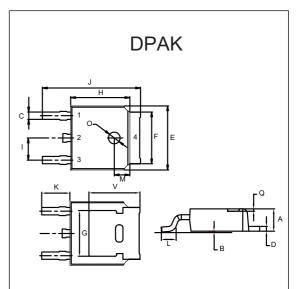
Parameter	Symbol	Rating	Unit	
Drain-Source Voltage		V _{DS}	20	V
Gate-Source Volltage		V _{GS}	±10	V
Continuous Drain Current	T _C =25°C		90	Α
	T _C =100°C	l _D	63	Α
Pulsed Drain Current (Note 1	I _{DM}	225	Α	
Single Pulse Avalanche Energy (Note 2)		E _{AS}	205	mJ
Total Power Dissipation	T _C =25°C	P _D	45	W
	T _C =100°C] 'D	23	W

Note:1. Pulse Test: Pulse Width \leq 300 μ s,Duty Cycle \leq 2%. 2.T $_J$ =25°C, V $_DD$ =15V, V $_G$ =10V, L=0.5mH, R $_g$ =25 Ω .

Internal Structure and Marking Code



N-CHANNEL MOSFET



DIMENSIONS					
DIM INCHES		MM		NOTE	
DIIVI	MIN	MAX	MIN	MAX	NOTE
Α	0.087	0.094	2.20	2.40	
В	0.000	0.005	0.00	0.13	
С	0.026	0.034	0.66	0.86	
D	0.018	0.023	0.46	0.58	
Е	0.256	0.264	6.50	6.70	
F	0.201	0.215	5.10	5.46	
G	0.190		4.83		TYP.
Н	0.236	0.244	6.00	6.20	
ı	0.086	0.094	2.18	2.39	
J	0.386	0.409	9.80	10.40	
K	0.114		2.90		TYP.
L	0.055	0.067	1.40	1.70	
М	0.063		1.60		TYP.
0	0.043	0.051	1.10	1.30	
Q	0.000	0.012	0.00	0.30	
V	0.211		5.35		TYP.

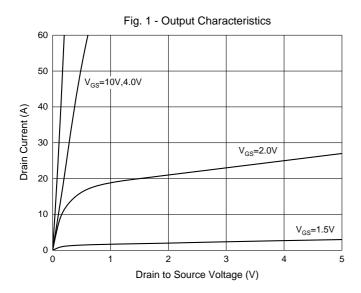


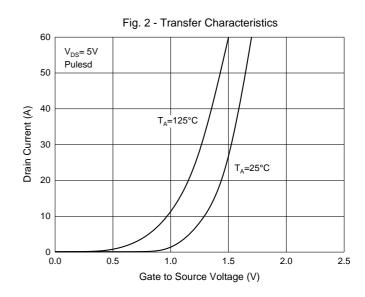
Electrical Characteristics @ 25°C (Unless Otherwise Specified)

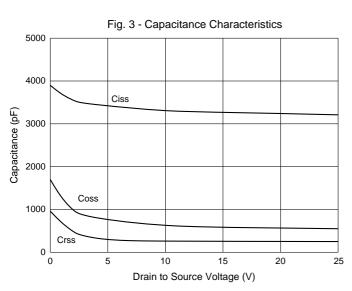
Parameter	Symbol	Test Conditions	Min	Тур	Max	Unit	
Static Characteristics						,	
Drain-Source Breakdown Voltage	V _{(BR)DSS}	V _{GS} =0V, I _D =250μA	20			V	
Gate-Source Leakage Current	I _{GSS}	V _{DS} =0V, V _{GS} =±10V			±100	nA	
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =20V, V _{GS} =0V			1	μA	
Gate-Threshold Voltage	V _{GS(th)}	V _{DS} =V _{GS} , I _D =250μA	0.4	0.62	1	V	
Drain-Source On-Resistance		V _{GS} =4.5V, I _D =20A		2.8	4.5	mΩ	
	R _{DS(on)}	V _{GS} =2.5V, I _D =15A		3.3	5		
		V _{GS} =1.8V, I _D =10A		4.7	7.5		
Diode Forward Voltage	V _{SD}	V _{GS} =0V, I _S =20A		0.8	1.2	V	
Continuous Body Diode Current	Is				90	Α	
Dynamic Characteristics							
Input Capacitance	C _{iss}			3250		pF	
Output Capacitance	C _{oss}	V _{DS} =10V,V _{GS} =0V,f=1MHz		580			
Reverse Transfer Capacitance	C _{rss}			275			
Total Gate Charge	Q_g			105		- nC	
Gate-Source Charge	Q _{gs}	V _{DS} =10V,V _{GS} =4.5V,I _D =15A		25			
Gate-Drain Charge	Q_{gd}			21			
Reverse Recovery Chrage	Q _{rr}	1 =15 \ di/dt=100 \ \ / \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \		39			
Reverse Recovery Time	t _{rr}	I _S =15A, di/dt=100A/μs		35			
Turn-On Delay Time	t _{d(on)}			12			
Turn-On Rise Time	t _r	V_{GS} =4.5V, V_{DD} =10V, I_{D} =10A, R_{L} =1 Ω		26		ns	
Turn-Off Delay Time	t _{d(off)}	R_{GEN} =3 Ω		35			
Turn-Off Fall Time	t _f			10			

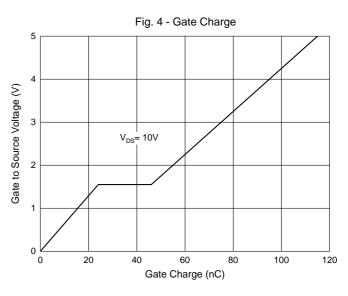


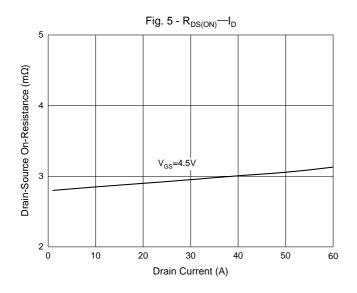
Curve Characteristics

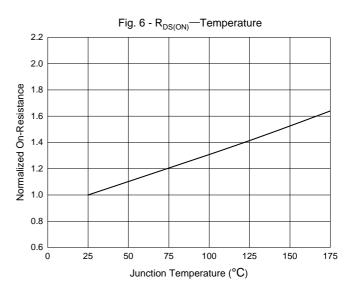














Ordering Information

Device	Packing
Part Number-TP	Tape&Reel: 2.5Kpcs/Reel

Note: Adding "-HF" Suffix for Halogen Free, eg. Part Number-TP-HF

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